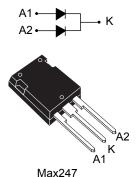




100 V power Schottky rectifier



Features

- · High reverse voltage
- · Negligible switching losses
- · Low forward voltage drop
- Low leakage current
- · High temperature
- · Low thermal resistance
- · Avalanche capability specified
- ECOPACK®2 compliant

Applications

- Switching diode
- SMPS
- DC/DC converter
- LED lighting
- · Desktop power supply

Description

This dual diode common cathode Schottky rectifier is suited for switched mode power supplies and high frequency DC to DC converters.

Packaged in Max247, the STPS80H100C is optimized for use in high frequency computer and telecom converters.

Product status				
STPS80H100C				
Product summary				
2 x 40 A				
100 V				
175 °C				
0.65 V				



1 Characteristics

Table 1. Absolute ratings (limiting values, per diode at 25 °C, unless otherwise specified)

Symbol	Symbol Parameter				Unit
V _{RRM}	Repetitive peak reverse voltage			100	V
I _{F(RMS)}	Forward rms current			50	Α
	A	T _C = 150 °C	Per diode	40	
IF(AV)	$I_{F(AV)}$ Average forward current, $\delta = 0.5$, square wave	T _C = 140 °C	Per device	80	Α
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinu	400	Α	
P _{ARM}	Repetitive peak avalanche power	lanche power t_p = 10 μ s, T_j = 125 $^{\circ}$ C			W
T _{stg}	Storage temperature range			-65 to +175	°C
Tj	Maximum operating junction temperature ⁽¹⁾			+175	°C

^{1.} $(dP_{tot}/dT_i) < (1/R_{th(i-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter		Max. value	Unit
D.,	Junction to case	Per diode	0.7	°C/W
R _{th(j-c)}	Junction to case	Total	0.5	C/VV
R _{th(c)}	Coupling		0.3	°C/W

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} x R_{\text{th(j-c)}} \text{ (per diode)} + P_{\text{(diode2)}} x R_{\text{th(c)}}$

For more information, please refer to the following application note:

· AN5088: Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	\/p = \/pp	-		20	μA
'R'	Neverse leakage current	$T_j = 125 ^{\circ}\text{C}$ $V_R = V_{RRM}$		-	7	20	mA
	Forward voltage drop	T _j = 25 °C	I _F = 40 A	-		0.80	
V ₋ (2)		T _j = 125 °C		-	0.65	0.70	V
VF * 7		T _j = 25 °C		-		0.94	v
		T _j = 125 °C		-	0.79	0.84	

- 1. Pulse test: $t_p = 5$ ms, $\delta < 2\%$
- 2. Pulse test: t_p =380 μ s, δ < 2%

To evaluate the conduction losses, use the following equation: $P = 0.56 \times I_{F(AV)} + 0.0035 \times I_{F}^{2}$ (RMS) For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode



1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current (per diode)

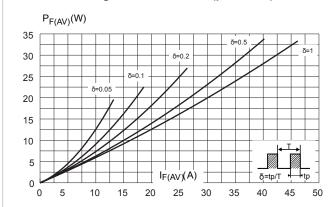


Figure 2. Average forward current versus ambient temperature (δ = 0.5, per diode)

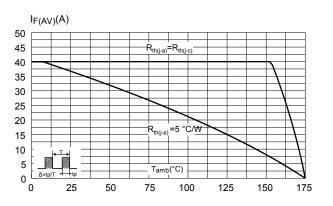


Figure 3. Normalized avalanche power derating versus pulse duration (T_i= 125 °C)

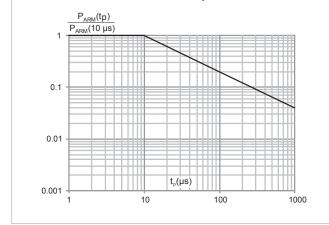


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

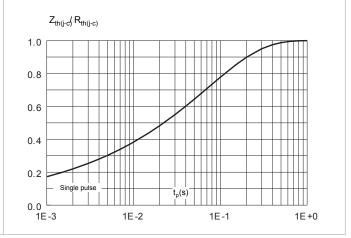




Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)

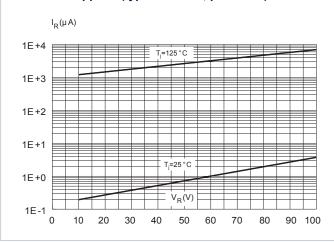


Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

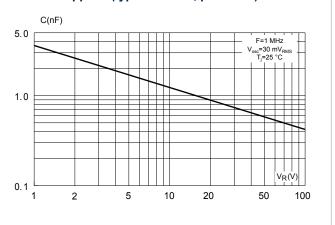
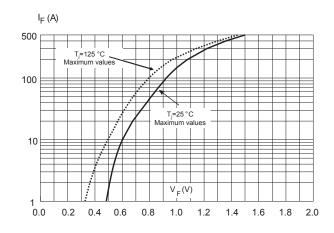


Figure 7. Forward voltage drop versus forward current (maximum values, per diode)





2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.



2.1 Max247 package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

Figure 8. Max247 package outline

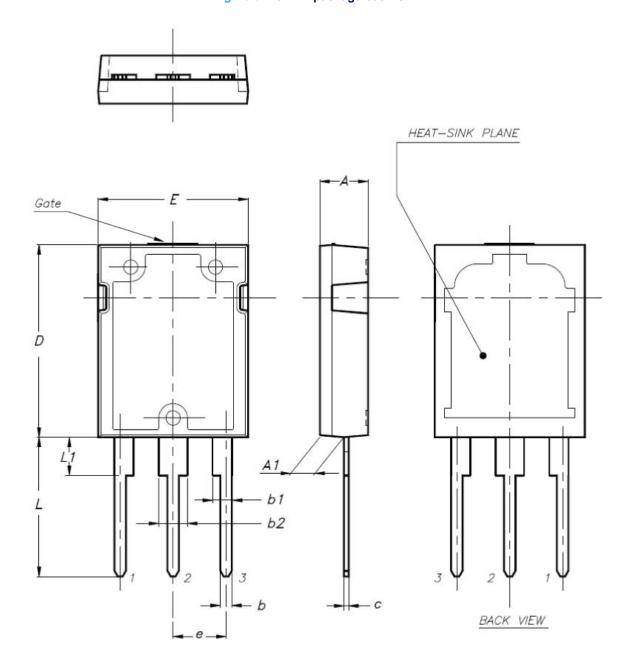




Table 4. Max247 package mechanical data

	Dimensions				
Ref.	Millin	neters	Inches (for reference only)		
	Min.	Max.	Min.	Max.	
А	4.70	5.30	0.185	0.208	
A1	2.20	2.60	0.086	0.102	
b	1.00	1.40	0.039	0.055	
b1	2.00	2.40	0.078	0.094	
b2	3.0	3.40	0.118	0.133	
С	0.40	0.80	0.015	0.031	
D	19.70	20.30	0.775	0.800	
E	15.30	15.90	0.602	0.626	
е	5.35	5.55	0.210	0.218	
L	14.20	15.20	0.559	0.598	
L1	3.70	4.30	0.145	0.169	



3 Ordering information

Table 5. Order code

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS80H100CY	STPS80H100CY	Max247	4.90 g	30	Tube



Revision history

Table 6. Document revision history

Date	Revision	Changes
July-2003	2B	Last release.
21-Jun-2010	3	Updated package illustration on page 1 and Section 2: Package information on page 5.
02-Jul-2018	4	Updated Figure 3. Normalized avalanche power derating versus pulse duration (T _j = 125 °C) and Table 1. Absolute ratings (limiting values, per diode at 25 °C, unless otherwise specified).



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